# UNISONIC TECHNOLOGIES CO., LTD

### BTC1510F3

#### NPN SILICON TRANSISTOR

## NPN EPITAXIAL PLANAR TRANSISTOR

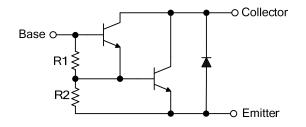
#### DESCRIPTION

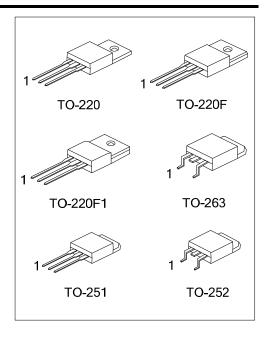
As a NPN Darlington transistor the UTC **BTC1510F3** is designed for general purpose amplifier and low speed switching application.

#### **■ FEATURES**

- \* Very high BV<sub>CEO</sub>
- \* Very low V<sub>CE(SAT)</sub>
- \* Very high current gain

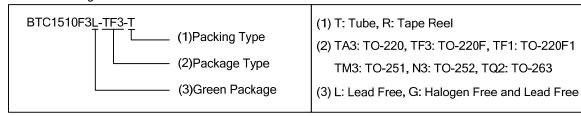
#### **■ EQUIVALENT CIRCUIT**



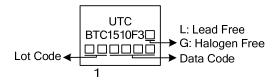


#### ■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Dooking	
Lead Free	Halogen Free	Fackage	1	2	3	Packing	
BTC1510F3L-TA3-T	BTC1510F3G-TA3-T	TO-220	В	С	Е	Tube	
BTC1510F3L-TF3-T	BTC1510F3G-TF3-T	TO-220F	В	С	Е	Tube	
BTC1510F3L-TF1-T	BTC1510F3G-TF1-T	TO-220F1	В	С	Е	Tube	
BTC1510F3L-TM3-T	BTC1510F3G-TM3-T	TO-251	В	С	Е	Tube	
BTC1510F3L-TN3-R	BTC1510F3G-TN3-R	TO-252	В	С	Е	Tape Reel	
BTC1510F3L-TQ2-T	BTC1510F3G-TQ2-T	TO-263	В	С	Е	Tube	
BTC1510F3L-TQ2-R	BTC1510F3G-TQ2-R	TO-263	В	С	Е	Tape Reel	



#### **■ MARKING**



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#### ■ **ABSOLUTE MAXIMUM RATING** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Base Voltage		V <sub>CBO</sub>	150	V	
Collector-Emitter Voltage		V <sub>CEO</sub>	150	V	
Emitter-Base Voltage		$V_{EBO}$	5	V	
Collector Current	DC		I.	10	Α
	Pulse(Note 2)		Ic	15	
Collector Dissipation	T <sub>A</sub> =25°C	TO-220/TO-220F TO-220F1	P <sub>D</sub>	2	W
		TO-251/TO-252		1.1	W
		TO-263		2	W
	T <sub>C</sub> =25°C	TO-220		72	W
		TO-220F/TO-220F1		36	W
		TO-251/TO-252		44	
		TO-263		60	W
Junction Temperature		TJ	150	°C	
Storage Temperature		$T_{STG}$	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

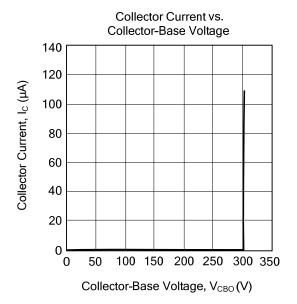
2. Pulse test: Pulse Width=100ms

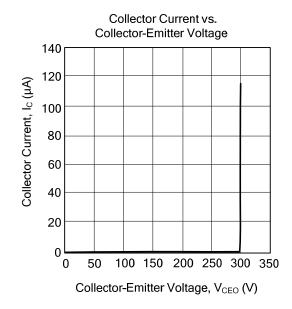
#### **■ ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	I <sub>C</sub> =100μA, I <sub>E</sub> =0	150			V	
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =5mA, I <sub>B</sub> =0	150			V	
Base-Emitter Turn-On Voltage (Note)	V <sub>BE(ON)</sub>	$V_{CE}$ =3 $V$ , $I_{C}$ =5 $A$			2.8	V	
		V <sub>CE</sub> =3V, I <sub>C</sub> =10A			4.5	V	
	$V_{FEC}$	I <sub>C</sub> =5A			3	V	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =150V, I <sub>E</sub> =0			200	μΑ	
Collector Cutoff Current	I <sub>CEO</sub>	V <sub>CE</sub> =150V, I <sub>E</sub> =0			200	μΑ	
Emitter Cutoff Current	I <sub>EBO</sub>	$V_{EB}$ =5V, $I_C$ =0			2	mA	
ON CHARACTERISTICS							
DC Current Gain (Note)	h <sub>FE</sub>	$V_{CE}$ =3V, $I_{C}$ =5A	2		20	K	
De Garrett Gairi (Note)		$V_{CE}$ =3V, $I_{C}$ =10A	100				
Base-Emitter Saturation Voltage(Note)	$V_{BE(SAT)}$	I <sub>C</sub> =5A, I <sub>B</sub> =5mA			2	V	
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =5A, I <sub>B</sub> =10mA			2	٧	
(Note)		I <sub>C</sub> =10A, I <sub>B</sub> =100mA			3		
(NOIC)		I <sub>C</sub> =5A, I <sub>B</sub> =2.5mA			1.5		

Note: Pulse test: Pulse Width  $\leq$  380 $\mu$ s, Duty Cycle  $\leq$  2%

#### ■ TYPICAL CHARACTERISTICS





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